# **Protected TRIAC**

# **Silicon Bidirectional Thyristor**

Designed for use in solid state relays, MPU interface, TTL logic and any other light industrial or consumer application. Supplied in an inexpensive TO-92 package which is readily adaptable for use in automatic insertion equipment.

#### **Features**

- One-Piece, Injection-Molded Package
- Blocking Voltage to 600 V
- Sensitive Gate Triggering in Two Trigger Modes (Quadrants)
- Improved Noise Immunity (dv/dt Minimum of 500 V/µsec at 125°C)
- Compliant with IEC6100-4-5
- High Surge Current of 8 A
- These are Pb-Free Devices

## MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (Sine Wave, 50 to 60 Hz, Gate Open, T <sub>J</sub> = 25 to 125°C)	V <sub>DRM,</sub> V <sub>RRM</sub>	600	V
On–State Current RMS (T <sub>C</sub> = 80°C) (Full Sine Wave 50 to 60 Hz)	I <sub>T(RMS)</sub>	0.8	Α
Peak Non-repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>C</sub> = 25°C)	I <sub>TSM</sub>	8.0	Α
Circuit Fusing Considerations (Pulse Width = 8.3 ms)	I <sup>2</sup> t	0.4	A <sup>2</sup> s
Peak Gate Power $(T_C = 80^{\circ}C, \text{ Pulse Width } \leq 1.0 \mu\text{s})$	P <sub>GM</sub>	5.0	W
Average Gate Power (T <sub>C</sub> = 80°C, t = 8.3 ms)	P <sub>G(AV)</sub>	0.1	W
Non-Repetitive Line Peak Voltage (IEC6100-4-5)	V <sub>PP</sub>	2.0	kV
Critical Rate of Rise of All–State Current ( $I_G = 2 \times I_{GT}$ , $t_r < 100 \ \mu s$ , $T_J = 125 ^{\circ}C$ )	di/dt	100	A/μs
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

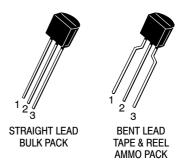


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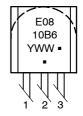
# PROTECTED TRIAC 0.8 AMPERE RMS 600 VOLTS





TO-92 (TO-226AA) CASE 029-11

#### **MARKING DIAGRAM**



x = 3,7,9
 Y = Year
 WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

	PIN ASSIGNMENT		
	1	OUT	
	2	Gate	
	3	СОМ	
L			

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

## THERMAL CHARACTERISTICS

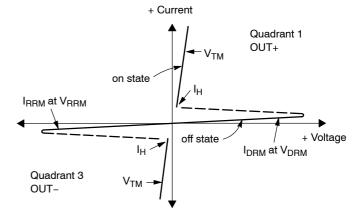
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient PCB Mounted per Figure TBD	$R_{\theta JA}$	156	°C/W
Thermal Resistance, Junction-to-Tab Measured on OUT Tab Adjacent to Epoxy	$R_{ heta JT}$	25	°C/W
Maximum Device Temperature for Soldering Purposes for 10 Secs Maximum	TL	260	°C

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

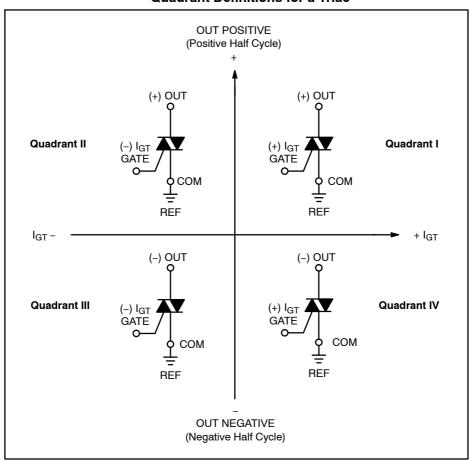
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•	
$ \begin{array}{ll} \mbox{Peak Repetitive Blocking Current} & T_{J} = 25^{\circ}\mbox{C} \\ \mbox{($V_{D}$ = Rated $V_{DRM}/V_{RRM}$; Gate Open)} & T_{J} = +125^{\circ}\mbox{C} \\ \end{array} $	I <sub>DRM</sub> , I <sub>RRM</sub>	- -	- -	2.0 200	μ <b>Α</b> μ <b>Α</b>
ON CHARACTERISTICS					
Peak On-State Voltage (I <sub>TM</sub> = ±1.1 A Peak; Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2.0%)	V <sub>TM</sub>	_	_	1.3	V
Gate Trigger Current (dc) $ (V_D = 12 \text{ Vdc, R}_L = 30 \ \Omega) \\ OUT(+), G(-) \\ OUT(-), G(-) $	I <sub>GT</sub>	0.15 0.15	- -	10 10	mA
Latching Current ( $V_D$ = 12 V, $I_G$ = 1.2 x $I_{GT}$ ) OUT(+), G(-) All Types OUT(-), G(-) All Types	ΙL	- -	- -	30 30	mA
Gate Trigger Voltage (dc) ( $V_D$ = 12 Vdc, $R_L$ = 30 $\Omega$ )	V <sub>GT</sub>	=	-	1.0	V
Gate Non-Trigger Voltage ( $V_D$ = 12 V, $R_L$ = 30 $\Omega$ , $T_J$ = 125°C) Quadrants 2, 3	$V_{GD}$	0.15	-	-	V
Dynamic Resistance	$R_D$	_	_	300	mΩ
Holding Current (V <sub>D</sub> = 12 Vdc, Initiating Current = 50 mA, Gate Open)	I <sub>H</sub>	_	-	25	mA
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current (Commutating dv/dt = 15 V/ $\mu$ s, Gate Open, T <sub>J</sub> = 125°C, f = 250 Hz, without Snubber)	di/dt(c)	0.3	-	-	A/ms
Critical Rate of Rise of Off–State Voltage ( $V_D$ = 67% $V_{DRM}$ , Exponential Waveform, Gate Open, $T_J$ = 125°C)	dv/dt	500	-	-	V/μs
Clamping Voltage ( $I_{CL} = 1.0 \text{ mA}$ , $t_p = 1 \text{ ms}$ , $T_J = 125^{\circ}\text{C}$ )	$V_{CL}$	650	-	-	V

# Voltage Current Characteristic of Triacs (Bidirectional Device)

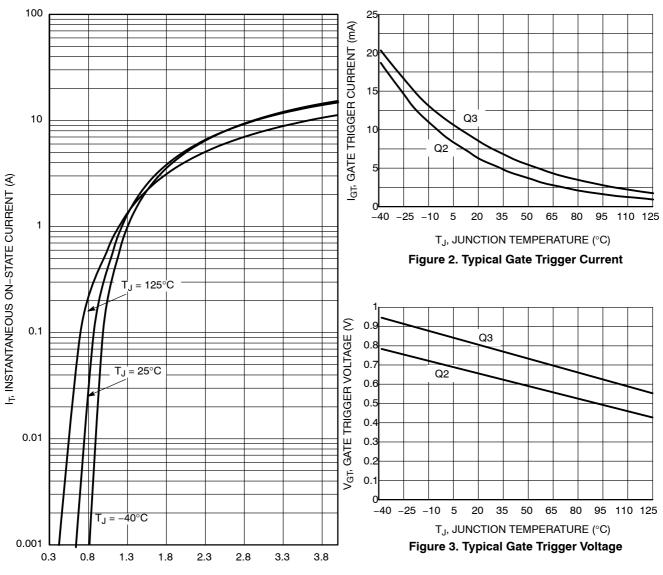
Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current



## **Quadrant Definitions for a Triac**

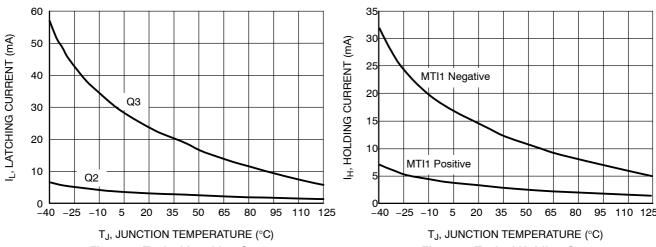


All polarities are referenced to COM.



V<sub>T</sub>, INSTANTANEOUS ON-STATE VOLTAGE (V)

Figure 1. Maximum On-State Voltage Characteristics



**Figure 4. Typical Latching Current** 

**Figure 5. Typical Holding Current** 

# TO-92 EIA RADIAL TAPE IN FAN FOLD BOX OR ON REEL

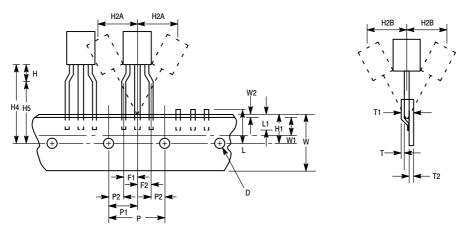


Figure 6. Device Positioning on Tape

		Specification			
		Inc	hes	Millin	neter
Symbol	Item	Min	Max	Min	Max
D	Tape Feedhole Diameter	0.1496	0.1653	3.8	4.2
D2	Component Lead Thickness Dimension	0.015	0.020	0.38	0.51
F1, F2	Component Lead Pitch	0.0945	0.110	2.4	2.8
Н	Bottom of Component to Seating Plane	0.059	0.156	1.5	4.0
H1	Feedhole Location	0.3346	0.3741	8.5	9.5
H2A	Deflection Left or Right	0	0.039	0	1.0
H2B	Deflection Front or Rear	0	0.051	0	1.0
H4	Feedhole to Bottom of Component	0.7086	0.768	18	19.5
H5	Feedhole to Seating Plane	0.610	0.649	15.5	16.5
L	Defective Unit Clipped Dimension	0.3346	0.433	8.5	11
L1	Lead Wire Enclosure	0.09842	-	2.5	-
Р	Feedhole Pitch	0.4921	0.5079	12.5	12.9
P1	Feedhole Center to Center Lead	0.2342	0.2658	5.95	6.75
P2	First Lead Spacing Dimension	0.1397	0.1556	3.55	3.95
Т	Adhesive Tape Thickness	0.06	0.08	0.15	0.20
T1	Overall Taped Package Thickness	-	0.0567	-	1.44
T2	Carrier Strip Thickness	0.014	0.027	0.35	0.65
W	Carrier Strip Width	0.6889	0.7481	17.5	19
W1	Adhesive Tape Width	0.2165	0.2841	5.5	6.3
W2	Adhesive Tape Position	.0059	0.01968	0.15	0.5

- Maximum alignment deviation between leads not to be greater than 0.2 mm.
   Defective components shall be clipped from the carrier tape such that the remaining protrusion (L) does not exceed a maximum of 11 mm.
- 4. Component lead to tape adhesion must meet the pull test requirements.
- Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
   Holddown tape not to extend beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
- No more than 1 consecutive missing component is permitted.
   A tape trailer and leader, having at least three feed holes is required before the first and after the last component.
- 9. Splices will not interfere with the sprocket feed holes.

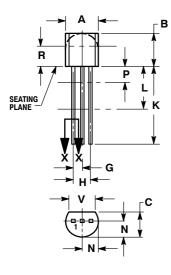
# ORDERING & SHIPPING INFORMATION: Packaging Options, Device Suffix

Device				
U.S.	Europe Equivalent	Description of TO-92 Tape Orientation	Package	Shipping
	NYE08-10B6RL1G	Flat side of TO-92 and adhesive tape visible	TO-92 (Pb-Free)	Radial 2000 / Tape and Reel
NYE08-10B6TG		N/A, Bulk	TO-92 (Pb-Free)	5000 Units / Box
NYE08-10B6RLRP	G	Round side of TO-92 and adhesive tape visible	TO-92 (Pb-Free)	Radial Tape and Fan Fold Box (2000 Units / Box)
NYE08-10B6RLRF	G	Round side of TO-92 and adhesive tape on reverse side	TO-92 (Pb-Free)	Radial Tape and Fan Fold Box (2000 Units / Box)

#### PACKAGE DIMENSIONS

## TO-92 (TO-226AA)

CASE 029-11 ISSUE AM



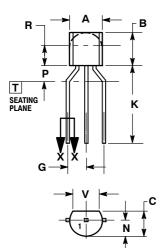
STRAIGHT LEAD **BULK PACK** 



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



**BENT LEAD** TAPE & REEL AMMO PACK



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  CONTOUR OF PACKAGE BEYOND

- DIMENSION R IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P
  AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

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8G-TR Z0109NN0,135 T2535T-8I T2535T-8T TN4050-12WL MAC4DLM-1G BT137-600E,127 BT137X-600D BT148W-600R,115

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